

Properties of Single Crystal Sapphire

Chemical Properties

Extremely high chemical stability in many acid environments even at high temperatures.

Chemical formula:

99,997 Al₂O₃

Physical Properties

Anisotropy, properties largely dependent on crystallographic orientation. High mechanical strength for high-pressure and shock-loading applications. Excellent rain erosion resistance and low frictional coefficient.

Crystal structure:

rhombohedral type single crystal, $a = 4,758 \text{ \AA}$; $c = 12,991 \text{ \AA}$

Density:

3,98g/cm³ ; 20 °C

Hardness:

Mohs 9 (Knoop 2200, Flat// to C-axis; 1900 Flat \perp to C-axis)

Tensile strength:

0,4 GPa at 25 °C; 0,35 GPa at 1000 °C

Compressive strength:

2,1 GPa at 25 °C

Flexural strength:

0,6 GPa at 25 °C

Young's modulus:

350 GPa at 25 °C

Compressive modulus:

380 GPa at 25 °C

Flexural modulus:

360 GPa at 25 °C

Rigidity modulus:

150 GPa at 25 °C

Bulk modulus:

240 GPa at 25 °C

Poisson's ratio:

0,29

Frictional coefficient:

Sapphire – Steel: 0,15; Sapphire - Sapphire: 0,1

Thermal Properties

High thermal conductivity, particularly at cryogenic temperatures, thermal shock resistance.

Melting point:

2053 °C

Application temperature:

2000 °C

Thermal expansion:

$6,2 \cdot 10^{-6} \text{ } ^\circ\text{C}^{-1}$ (20- 50 °C), // to C-axis; $5,4 \cdot 10^{-6} \text{ } ^\circ\text{C}^{-1}$ (50°C), \perp to C

Heat capacity:

18,6 cal/(Mol \cdot °C), (25°C); 30 cal/(Mol \cdot °C), (1000°C)

Thermal conductivity:

40 W/m $^\circ$ K (25°C); 12 W/m $^\circ$ K (400 °C); 4 W/m $^\circ$ K (1200 °C)
(phenomenal 10 000 W/m $^\circ$ K at -200°C)

Specific heat:

0,1 cal g⁻¹ °C⁻¹ (25 °C)

Optical Properties

High transparency from the ultraviolet (~0,2 μ m) through the visible, near infrared (6.5 μ m) and again from about 50 microns out through the microwave spectrum.

Fraction:

1,8 (@ 0,3 μ), 1,6 (@5 μ)

Optical transmission:

0,17- 6 μ m

Reflection loss:

12% (1 μ , by 2 surfaces)

Electrical Properties

High electrical resistivity, dielectric constant and strength.

Electrical resistivity:

10¹⁶ Ohm \cdot cm (20°C); 10¹¹ Ohm \cdot cm (500°C)

Dielectric constant:

11,6 // to C-axis; 9,4 \perp to C-axis, at 25°C, (10³- 10¹⁰ Hz)

Dielectric strength:

480 kV cm⁻¹ (60 Hz)

Dielectric dissipation:

0,00006 // to C-axis; 0,00003 \perp to C-axis (10 GHz)